

No. 139 Wuhan Rd., Longtan Township, Taoyuan County, Taiwan 32549 Tel: +886-3-4993132 Fax: +886-3-4991561 www.gradconn.com

# PRODUCT SPECIFICATION

GradConn Part No.:

CH03-FB

Product Description:

Micro 3FF SIM Card Connector





### **1.0 Product Specification**

## 1.1 Features

ETSI TS 102 221 Standard Micro SIM Card.

### 2.0 Technical Characteristics

2.1 General Characteristics				
Items	Standard	Description		
Dimension		13.40L x 13.40W x 2.40H mm.		
Weight		Approx. 0.50g.		
Card Size	ETSI.TS.102.221	15.00 x 12.00 x 0.76 mm.		
Contact Principle		Friction technology.		
Mounting System		SMT Type (without post).		
Durability		5,000 cycles min.		
Material				
Insulator		Thermoplastic UL94V-0.		
Data Contact		Phosphor Bronze.		
Cover		SUS(304).		
Plating		Gold over Nickel .		

2.2 Electrical Characteristics (According to Standard IEC512)					
Items	Standard	Description			
Number of contacts		6, 8 pins (optional).			
Contact highly		0.70±0.05mm.			
Rated voltage		50 V max.			
Rated current		1 A max. 10μ A min.			
Contact resistance	IEC512-2-2a	100mΩ max.			
Insulation resistance pin to pin	IEC512-2-3a	>1000 MΩ/500 VDC.			
Dielectric withstanding voltage	IEC512-2-4a	500 V AC rms 1 min. (sea level).			



2.3 Mechanical Characteristics				
Items	Standard	Description		
Card insertion force		20N Max.		
Card retention force		1N min.		
Contact location	ETSI.TS.102.221.			
Normal force		Min. 0.5N.		
Contact retention force		>1.0N.		

2.4 Solderability		
Items	Standard	Description
Wave	IEC-68-2-20.	Not Applicable.
Vaporphase		215°C, 30sec. max.
IR reflow		260°C, 10 sec. max.
Manual soldering	IEC68-2-20.	Not Applicable.

2.5 Environmental Characteristics (According to Standard IEC68)				
Items	Standard	Description		
Operating temperature		-40°C ~ + 85°C.		
Operating humidity		10% ~ 95% RH.		
Storage temperature		- 40°C ~ + 85°C.		
Storage humidity		10% ~ 95% RH.		
Thermal Shock		-40°C ~ +85°C, 5 cycles.		
Damp heat		40°C, 90%RH, 10 days.		
Salt-mist		35°C, 5% NaCl, 24HR.		



### 3.0 Interface

3.1 Signals		
Contact No	Assignment	Description
C1	Vcc	Power Voltage.
C2	RST	Reset signal.
C3	CLK	Clocking signal.
C4	RFU	Reserved for future use.
C5	GND	Power and signal ground.
C6	Vpp	Programming voltage.
C7	I/O	Serial data input/output.
C8	RFU	Reserved for future use.

3.2 Micro SIM Card Contact Location (ETSI TS 102 221)





## 4.0 Test Data

11 Durabilit							
Refore Test	y						
Purpose:	1. To test the mating/unmating force before and after 5,000 cycles mating.						
Standard:	Z. Dro						
Januaru.		Dut the next on t	ootor				
Iest Mothod:	」. つ	Ful the part on to	Ester. 5mm/min				
Increat	Z. 1						
Inspect	ו. כ	Withdraw Force.	Min 1N				
	2. 3	Low Level Conta	act Resistance <sup>,</sup> <100m	0			
	0.			ita			
Sample		Appearance         Insertion Force (N)         Withdrawal Force (N)         Contact (N)				Result	
1		No damage	5.34	3.25	9.09	Ok	
2		No damage	5.46	2.89	9.47	Ok	
3		No damage	5.71	3.16	9.17	Ok	
4		No damage	6.29	3.08	8.53	Ok	
5		No damage	5.95	3.05	8.74	Ok	
After 5000 c	vcle	S.					
Standard: Pr	, odu	ct spec.					
Inspect Item:	<ol> <li>Contact deform, damage.</li> <li>Insertion Force: Max 20N.</li> <li>Withdraw Force: Min 1N.</li> </ol>						
	<u>т.</u>	Low Level Conta		ita			
Sample		Data           Appearance         Insertion Force (N)         Withdrawal Force (N)         Contact Resistance (mΩ)         Resu				Result	
1		No damage	7.45	6.09	9.09	Ok	
2		No damage	7.54	6.02	9.47	Ok	
3		No damage	7.49	6.07	9.17	Ok	
4		No damage	7.4	6.03	8.53	Ok	
5		No damage         7.51         5.98         8.74         Ok					
Adjustment	Ok						



4.2 Normal Force						
Purpose:	Measure make sure	force required to push the termina e of a good contact with SIM card.	I down. Contacts require a prope	er normal force to		
Standard:	Product S	Spec				
Method:	1. Fix t 2. Start	ne part on jig, measure the distand the tester, write down the distanc	ce from contact to insulator surface e and force.	ce.		
Criteria:	Normal for	prce: Min 0.5N.				
San	nple Terminal Travelling (mm) Normal Force (N) Results					
	1 0.82 1.30 Ok					
	2 0.8 1.27 Ok					
	3 0.81 1.03 Ok					
4	4 0.8 0.97 Ok					
Ļ	5	0.85	0.97	Ok		

## 4.3 Contact Retention Force

Method:	Apply an axial	Apply an axial load to terminal, assembled in the housing at a speed of 25-50 mm/min.					
Equipment:	Mating/unmati	ng tester.					
Criteria:	>1N.						
Pin Sample	1	2	3	4	5	6	Result
1	2.37	2.88	2.13	2.78	2.01	3.01	Ok
2	2.14	2.12	2.56	3.02	3.14	2.89	Ok
3	2.22	2.21	2.88	3.04	3.02	2.11	Ok
4	3.16	3.14	2.99	2.31	3.01	2.15	Ok



4.4 Dielectric	4.4 Dielectric					
Purpose:	<ol> <li>Verify</li> <li>Verify</li> </ol>	v the performance of withstanc v the material insulation perform	ling rate voltage. mance.			
Standard:	Product S	Dec.				
Method:	<ol> <li>Test a</li> <li>Test d</li> <li>Leaka</li> </ol>	djacent pin: shell and closed p uration 1 min. ge current 0.2mA.	bin.			
Criteria:	500V/Minu	ite.				
Voltage:		500V/AC	Temp:		25°C	
Leakage curren	t:	0.02mA	Humidity:		60%	
Test duration:		60 Seconds	Unit:		V	
Sample		Record			Result	
1		No breakdown.			Ok	
2		No breakdown. Ok				
3		No breakdown. Ok			Ok	
4		No breakdown Ok			Ok	
5		No breakdown Ok				
	Pass					

4.5 Insulation Resistance					
Purpose:	Performance of the insulation resistance.				
Standard:	Product spec.				
Method:	<ol> <li>Apply on adjacent contact or contact and shell.</li> <li>Write down the min data if various data available.</li> <li>No breakdown, flashover.</li> </ol>				
Criteria:	>1000MΩ./min				
Sample Record Result					
1 1962MΩ Ok					
2 1847MΩ Ok					
3	3 1967MΩ Ok				

1694MΩ

4

5

Ok

Ok



4.6 Contact Res	4.6 Contact Resistance					
Purpose:	Verify the contact re	esistance.				
Standard:	Product spec.					
Method:	Measure the voltag	e drop at the circuit and work out the CR				
Criteria:	>80MΩ/max.					
Sa	ample	Record	Result			
	1 9.17mΩ Ok					
	2 8.93mΩ Ok					
	3 8.99mΩ Ok					
	4 9.78mΩ Ok					
	5 9.69mΩ Ok					
Pass						

4.7 IR Heat Resistant Test						
Purpose:	1. Check the contact and insulator stress after high temp.					
	2. Any other damage to the connector after high temp.					
Standard:	Product spec.					
Equipment:	IR reflow.					
Requirement:	<ol> <li>Sample without damage, bending, deforming or bubbles before test.</li> <li>Set IR Reflow temperature at 260°C (+/- 5°C), duration 7 minutes.</li> </ol>					
Criteria:	<ol> <li>No damage, bending, deforming or bubbles after test.</li> <li>Coplanairity ≤0.08mm.</li> </ol>					
Sample	Appearance	Deform	Bending	Bubble	Coplanairty	Result
1	Ok	Ok	Ok	Ok	0.08mm	Ok
2	Ok	Ok	Ok	Ok	0.07mm	Ok
3	Ok	Ok	Ok	Ok	0.07mm	Ok
4	Ok	Ok	Ok	Ok	0.08mm	Ok
5	Ok	Ok	Ok	Ok	0.05mm	Ok
Pass						



4.8 Salt Spray	,				
Setting:	1.	Tester Temp: 35±2°C.	6.	Solution PH: 6.5-7.5.	
	2.	Reservoir: 47±2°C.	7.	Solution speed: 1.0-2.0ml/80cm.	
	3.	Nozzle press: 0.7-1.0Kg/cm <sup>2</sup> .	8.	Dry temp: 80°C.	
	4.	Air press: 2.4Kg/cm <sup>2</sup> .	9.	Dry time: 30minutes.	
	5.	Concentration: 5±0.5%NaCl.	10.	Test time: 24H.	
Method:	1.	Clean and check samples.			
	2.	. Put into tester.			
	3.	3. Set Machine.			
	4. Clean the sample with water for 5 min and dry.				
Standard:	Product spec.				
Criteria:	No bubble, oxidation, corrosion, rust.				
Results:	Pass.				

4.9 Solderability						
Purpose:	se: 1. To verify the performance of solderability after plating.					
	2. Verify contact solderability.					
Standard:	Product spec.					
Method:	Method: Temp (255±5) °C, with speed of 1±0.25 (inch)/S dip into solder pot, duration 3-5 seconds.					
Sample		Criteria	Result			
1		95% with solder covered, no pin hole.	Ok			
2		95% with solder covered, no pin hole.	Ok			
3		95% with solder covered, no pin hole.	Ok			
4		95% with solder covered, no pin hole.	Ok			
5		95% with solder covered, no pin hole.	Ok			
Pass						

5.0 Dip Heat Resistant					
Purpose:	To verify the heat resistance on dip solder.				
Standard:	Product spec.				
Method:	Temp (255±5)°C, with speed of 1±0.25 (inch)/S dip into solder pot, duration 3-5 seconds.				
Criteria:	No crack, melt, deform.				
Sample		Criteria	Result		
1		No crack, melt, deform.	Ok		
2		No crack, melt, deform.	Ok		
3		No crack, melt, deform.	Ok		
4		No crack, melt, deform.	Ok		
5		No crack, melt, deform.	Ok		
Pass					